



# PJQ2407

## 30V P-Channel Enhancement Mode MOSFET

<b>Voltage</b>	<b>-30 V</b>	<b>Current</b>	<b>-8.4A</b>
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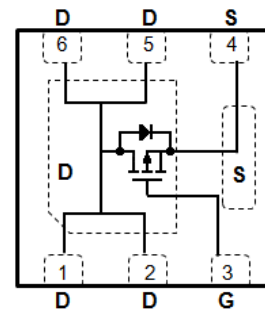
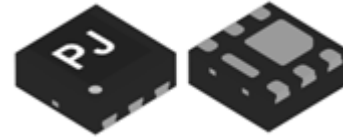
### Features

- $R_{DS(ON)}$ ,  $V_{GS}@-10V, I_D@-8.4A < 20m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}@-4.5V, I_D@-5A < 32m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC61249 standard

### Mechanical Data

- Case: DFN2020B-6L Package
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0003 ounces, 0.0086 grams

DFN2020B-6L



## Maximum Ratings and Thermal Characteristics ( $T_A=25^\circ\text{C}$ unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		$V_{DS}$	-30	V
Gate-Source Voltage		$V_{GS}$	$\pm 20$	V
Continuous Drain Current		$I_D$	-8.4	A
Pulsed Drain Current		$I_{DM}$	-33.6	
Power Dissipation	$T_a=25^\circ\text{C}$	$P_D$	2.0	W
	Derate above $25^\circ\text{C}$		16	mW/ $^\circ\text{C}$
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	$^\circ\text{C}$
Typical Thermal Resistance		$R_{\theta JA}$	62.5	$^\circ\text{C/W}$
- Junction to Ambient <sup>(Note 5)</sup>				



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## Electrical Characteristics (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
<b>Static</b>						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA	-30	-	-	V
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> , I <sub>D</sub> =-250uA	-1	-1.5	-2.5	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V, I <sub>D</sub> =-8.4A	-	17	20	mΩ
		V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-5A	-	26	32	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V	-	-	-1.0	uA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>GS</sub> =±20V, V <sub>DS</sub> =0V	-	-	±100	nA
<b>Dynamic</b> (Note 6)						
Total Gate Charge	Q <sub>g</sub>	V <sub>DS</sub> =-15V, I <sub>D</sub> =-5A, V <sub>GS</sub> =-4.5V (Note 1,2)	-	11	-	nC
Gate-Source Charge	Q <sub>gs</sub>		-	3.2	-	
Gate-Drain Charge	Q <sub>gd</sub>		-	3.9	-	
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =-15V, V <sub>GS</sub> =0V, f=1.0MHZ	-	1169	-	pF
Output Capacitance	C <sub>oss</sub>		-	180	-	
Reverse Transfer Capacitance	C <sub>rss</sub>		-	132	-	
Turn-On Delay Time	td <sub>(on)</sub>	V <sub>DS</sub> =-15V, I <sub>D</sub> =-1A, V <sub>GS</sub> =-10V, R <sub>G</sub> =6Ω (Note 1,2)	-	5.9	-	ns
Turn-On Rise Time	tr		-	33	-	
Turn-Off Delay Time	td <sub>(off)</sub>		-	55	-	
Turn-Off Fall Time	tf		-	34	-	
<b>Drain-Source Diode</b>						
Maximum Continuous Drain-Source Diode Forward Current	I <sub>S</sub>	---	-	-	-1.5	A
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> =-1A, V <sub>GS</sub> =0V	-	-0.73	-1	V

**NOTES :**

1. Pulse width ≤ 300us, Duty cycle ≤ 2%
2. Essentially independent of operating temperature typical characteristics.
3. The maximum current rating is package limited.
4. Repetitive rating, pulse width limited by junction temperature T<sub>J(MAX)</sub>=150°C. Ratings are based on low frequency and duty cycles to keep initial T<sub>J</sub>=25°C.
5. R<sub>θJA</sub> is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
6. Guaranteed by design, not subject to production testing.



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## TYPICAL CHARACTERISTIC CURVES

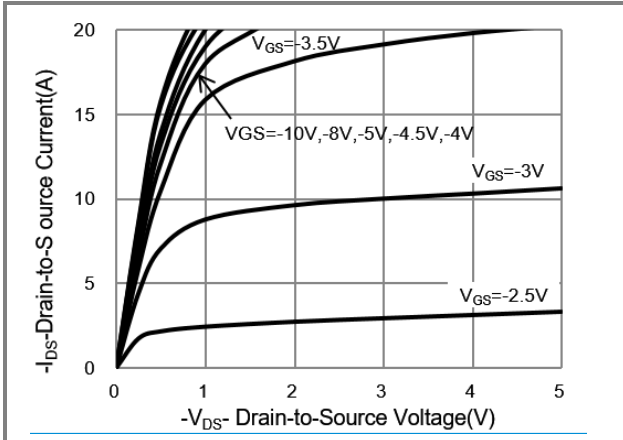


Fig.1 On-Region Characteristics

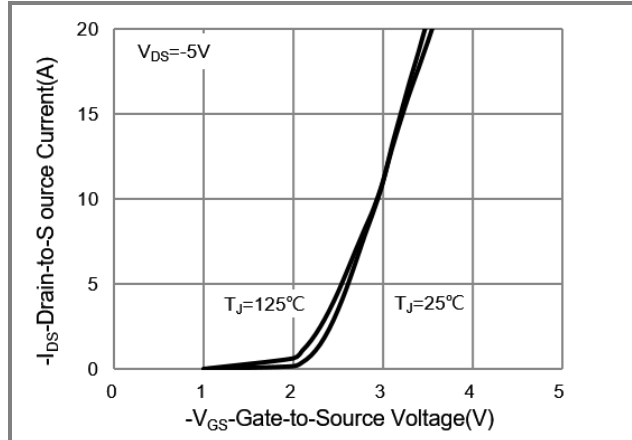


Fig.2 Transfer Characteristics

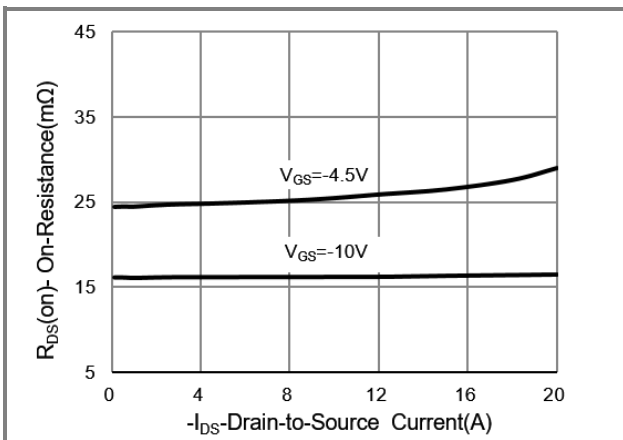


Fig.3 On-Resistance vs. Drain Current

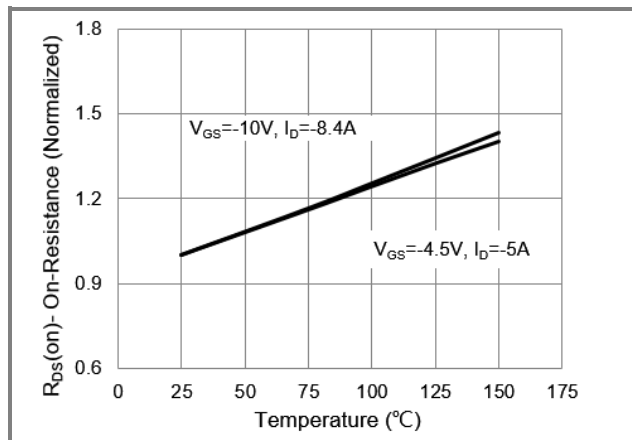


Fig.4 On-Resistance vs. Junction temperature

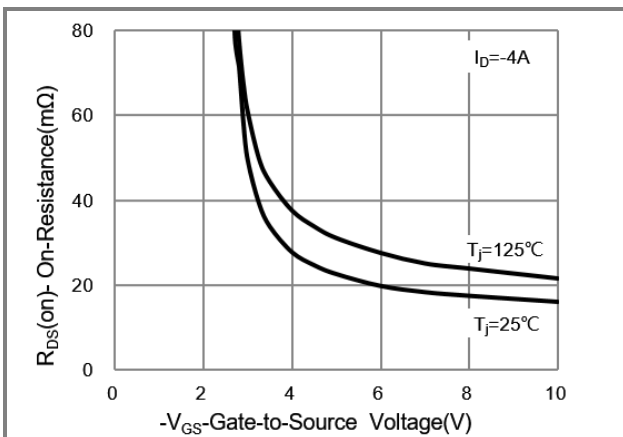


Fig.5 On-Resistance Variation with VGS.

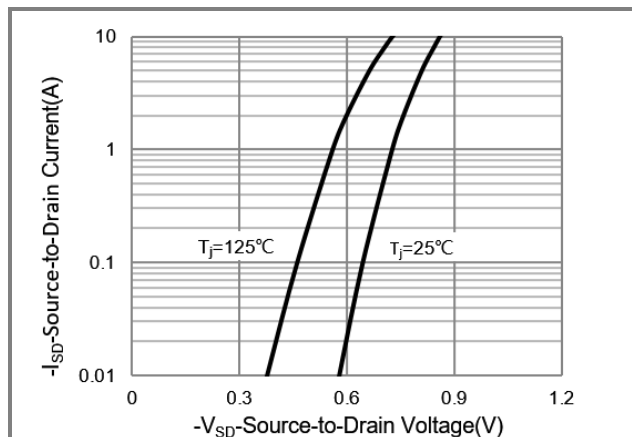


Fig.6 Body Diode Characteristics



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## TYPICAL CHARACTERISTIC CURVES

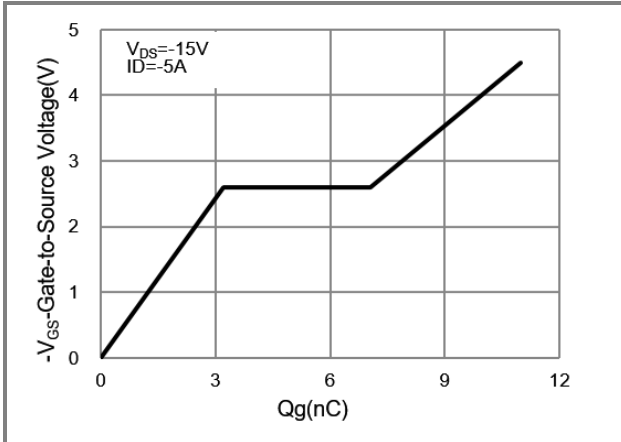


Fig.7 Gate-Charge Characteristics

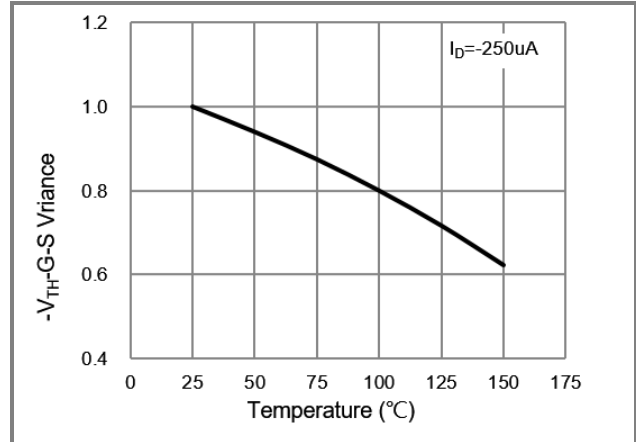


Fig.8 Threshold Voltage Variation with Temperature.

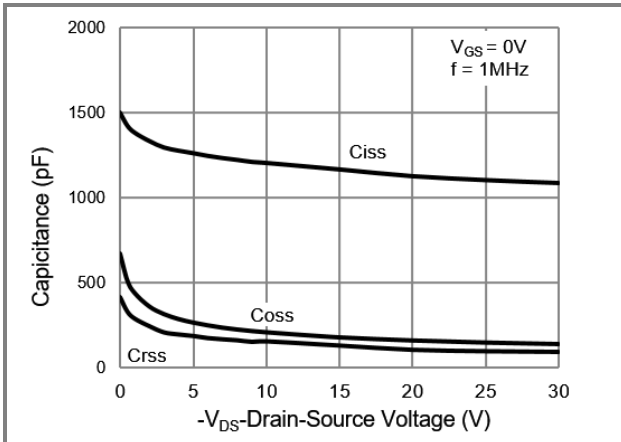


Fig.9 Capacitance vs. Drain-Source Voltage.

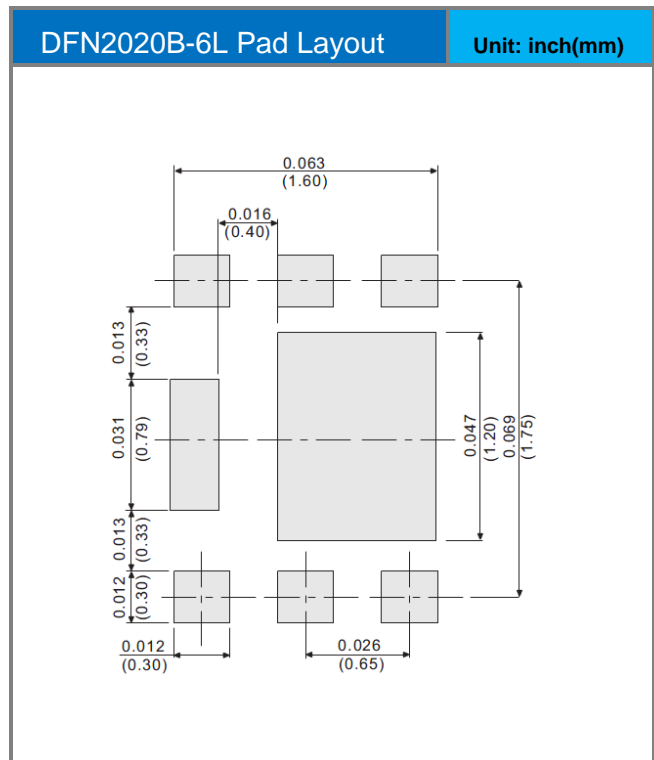
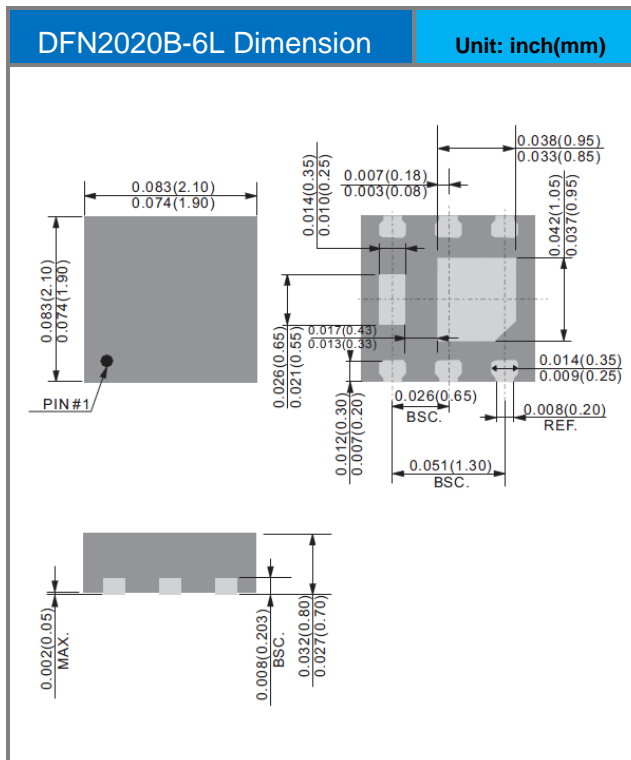


# PJQ2407

## PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing Type	Marking	Version
PJQ2407_R1_00001	DFN2020B-6L	3K pcs / 7" reel	407	Halogen free

## MOUNTING PAD LAYOUT





## PJQ2407

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